Dec.10

13:00-15:00

## Yokohama Media & Communications Center 6th floor

	13.00 13.00						Tokonama Media & Communications Center Cut moor		
Entry No	Presentation	Presenter_J(F amily)	Presenter_J(Fi	Presenter_E(F amily)	Presenter_E(Fi rst)	Affiliation	Paper Title(J)	Paper Title(E)	
	東京工科プ yo University o	・ 大学コンピュータ f Technology	サイエンス学部		•	Chair:Hiroshi			
		プドウェル研究所 d,/Mie University	· /三重大学大学  /	院工学研究科		Chair:Miyoshi			
	冒昭/愛媛大学ノ hime University	大学院理工学研	究科			Chair:Tomoaki			
10035	E-P10-001	野見山	輝明	NOMIYAMA	Teruaki	Graduate School of Science and Engineering KAGOSHIMA UNIVERSITY	メソポーラス銅酸化物の作製と光蓄電池への応用	Preparation of mesoporous Cu <sub>x</sub> O film and its application to photorechargeable battery	
10087	E-P10-002	中西	由貴	NAKANISHI	Yuki	Central Glass Co., Ltd.	反応性スパッタリング法で作製したAIドープZnO膜の成膜 速度の向上	Improvement in growth rate of Al-doped ZnO thin film deposited by reactive magnetron sputtering	
10393	E-P10-003	金子	俊幸	KANEKO	Toshiyuki	Kanazawa Institute of Technology	有機金属化学気相成長法によるBi <sub>2</sub> Sr <sub>2</sub> CaCu <sub>2</sub> O <sub>8+δ</sub> 超伝導 薄膜の作製と評価	Preparation and Evaluation of $Bi_2Sr_2CaCu_2O_{8+\delta}$ Superconducting Films by MOCVD	
10782	E-P10-004	押川	晃一郎	OSHIKAWA	Koichiro	Graduate School and Faculty of Information Science and Electrical Engineering, University of Kyushu	マグネトロンスパッタリングによる窒素添加結晶化法を用い た低抵抗透明酸化物半導体の作製	Magnetron sputtering of low-resistive transparent conductive oxide films with double buffer layers fabricated via nitrogen mediated crystallization	
10239	E-P10-005	岡田	聡	OKADA	Akira	Mie University		Double-layer Fabrication of Cubic-Manganites/Hexagonal- ZnO and p-n Junction Characteristics.	
10238	E-P10-006	森	俊貴	MORI	Toshiki	Graduate School of Electrical and Electronic Engineering , Mie University		Lattice Matching Calculations to Interpret In-plane Orientations of LSMO Grown on (0001)ZnO; Interface Distortion Energy and Coulombic Energy	
10377	E-P10-007	花田	和哉	HANADA	Kazuya	Graduate School of Electrical and Electronic Engineering, Mie University		Remarkable Differences in Heating Evolutions of Chemical Bonds in Plasma-irradiated and Non-irradiated PET Films	
10192	E-P10-008	上野	慎太郎	UENO	Shintaro	Interdisciplinary Graduate School of Medicine and Engineering, University of Yamanashi	湿式法による金属/誘電体複合キャパシタの低温作製	Low-Temperature Fabrication of Metal/Dielectrics Composite Capacitors by Wet Chemical Method	
10432	E-P10-009	大久保	知貴	OKUBO	Tomoki		クエン酸法により合成した酸素過剰のLn <sub>2</sub> NiO <sub>4+δ</sub> (Ln=La, Pr, Nd)の構造調査	Structural Investigation of Excess Oxygen–Containing $Ln_2{ m NiO}_{4+\delta}$ ( $Ln$ =La, Pr, Nd) Synthesized by a Citric–Acid Method	
10627	E-P10-010	太田	啓一	ОНТА	Keiichi	Mechanical Systems and Materials Engineering, Muroran Institute of Technology	リチウムアルミニウムチタネートの結晶構造解析	Crystal Structure Analysis of Lithium Aluminum Titanate	

Entry No	Presentation	Presenter_J(F amily)	Presenter_J(Fi rst)	Presenter_E(F amily)	Presenter_E(Fi	Affiliation	Paper Title(J)	Paper Title(E)
10628	E-P10-011	富田	靖正	TOMITA	Yasumasa	Graduate School of Engineering, University of Shizuoka	リチウム鉄シリケート系正極活物質の合成と二次電池特性	Synthesis of Lithium Iron Silicate and Characteristics for Cathode Active Materials of Secondary Battery.
10094	E-P10-012	中村	悟士	NAKUMURA	Satoshi	Tokyo University of Technology	衝撃圧縮法によるBi系酸化物超伝導体微粒子の作製と厚 膜化	Preparation of shocked Bi-superconducting particles for making thick films
10383	E-P10-013	中村	拓未	NAKAMURA	Takumi	Graduate school of Science & Technology, Nihon University	LiNbO <sub>3</sub> 基板上におけるCr <sub>2</sub> O <sub>3</sub> 薄膜の結晶成長	Crystal growth of the $\mathrm{Cr}_2\mathrm{O}_3$ thin films on $\mathrm{LiNbO}_3$ Substrates
10363	E-P10-014	林	佑太郎	HAYASHI	Yutaro	College of Science & Technology, Nihon University	YAIO <sub>3</sub> 基板上でのCr <sub>2</sub> O <sub>3</sub> 薄膜の作製	Crystal growth of the Cr <sub>2</sub> O <sub>3</sub> thin films on YAIO <sub>3</sub> substrate
10381	E-P10-015	大島	佳祐	OSHIMA	Keisuke	College of Science & Technology Nihon University	STO(100)およびSTO(110)基板上へのCaFeO <sub>x</sub> 薄膜の成長 と評価	Growth and Evaluation of $CaFeO_x$ Thin Films Grown on $SrTiO_3(100)$ and (110) substrates
10421	E-P10-016	稲葉	隆哲	INABA	Takaaki	College of Science and Technology, Nihon University	パスルレーザ堆積法によるBiMO <sub>3</sub> (M=Fe,Fe <sub>1-x</sub> Mn <sub>x</sub> )薄膜の作 製と評価	Preparation and Evaluation of BiMO <sub>3</sub> (M=Fe,Fe <sub>1-x</sub> Mn <sub>x</sub> )Thin Films Grown by Pulsed Laser Deposition Method
10795	E-P10-017	有沢	俊一	ARISAWA	Shunichi	National Institute for Materials Science	Local Current Stream around Holes with Various Shapes in Superconducting Thin Films Observed by Scanning SQUID Microscopy	Local Current Stream around Holes with Various Shapes in Superconducting Thin Films Observed by Scanning SQUID Microscopy
10342	E-P10-018	廣芝	伸哉	HIROSHIBA	Nobuya	Graduate School of Engineering, Nagoya Institute of Technology	WO <sub>3</sub> ナノ構造体の水熱合成、構造評価および光・電子物性	Solvo-thermal Synthesis, Structure and its Opt-Electronic Properties of Nanostructured $\mathrm{WO}_3$
10440	E-P10-019	伊藤	弘樹	ІТО	Hiroki	Graduate School of Engineering, Nagoya Institute of Technology	CVT法を用いたZnO高速成長におけるCO₂の効果	$\mathrm{CO}_2$ effect on high speed growth of ZnO crystals by using chemical vapor transport
10743	E-P10-020	松本	拓也	MATSUMOTO	Takuya	Graduate School of Engineering, Nagoya Institute of Technology	水溶液から作成するZnO薄膜の作製におけるZn源の影響	Zinc source effect on the ZnO thin films synthesized from aqueous solution
10361	E-P10-021	酒井	智啓	SAKAI	Tomohiro	Thin film lab, Nagoya institute of technology	ZnOシード層の熱処理によるZnOナノロッドの密度制御	Control of density ZnO nanorods using thermally treated ZnO seed-layer
10521	E-P10-022	寺迫	智昭	Terasako	Tomoaki		溶液成長法をベースとする手法によるp-CuO/n-ZnOヘテロ接合の形成	Fabrication of p-CuO/n-ZnO Heterojunctions by Chemical Bath Deposition Based Technique